Low-Power Dual Schmitt-Trigger Buffer

Description

The bus buffer gate is designed for 0.8-V to 3.6-V VCC operation.

The FLG74AUP2G17 device contains two buffers and performs the Boolean function Y = A .The device functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

The FLG74AUP2G17 device is available in a variety of packages, including SOT-23-6, SC70-6.

Features

- Inputs Accept Voltages 0.8V to 3.6 V
- Includes Schmitt-Trigger inputs
- Max Tpd of 5.4 ns at 3.3 V
- Low Static-Consumption, 0.5- μ A Max I_{CC}
- Low Noise Overshoot and Undershoot < 10% of V_{CC}
- Ioff Supports Live Insertion,Partial-Power-Down Mode, and Back-Drive Protection
- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at Input(V_{hys}= 250mV Typical 3.3V)
- 3.6V I/O Tolerant to Support Mixed-Mode Signal Operation
- Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 1000-V Charged-Device Model (C101)

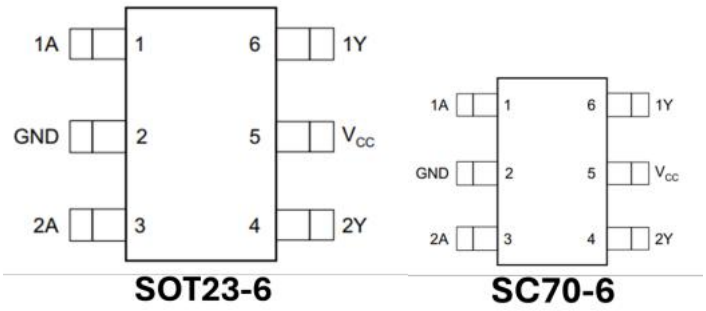
Applications

- Grid Infrastructure
- PC & Notebooks
- Tablets
- Factory Automation & Control
- Gaming
- Server

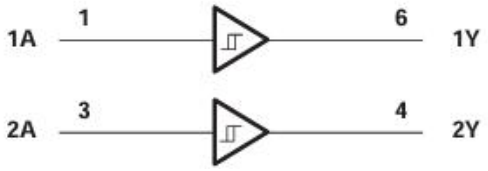
Order information

Mode	Package	Ordering Number	Packing Option
FLG74AUP2G17	SOT-23-6	FLG74AUP2G17YSOT236G/TR	Tape and Reel,3000
	SC70-6	FLG74AUP2G17YSC706G/TR	Tape and Reel,3000

Pin Configuration



Simplified Schematic



Pin Assignment

Pin Name	Pin No.	Pin Function
GND	2	Ground
1A	1	Input 1
2A	3	Input 2
1Y	6	Open-drain output 1
2Y	4	Open-drain output 2
VCC	5	Power pin

Absolute Maximum Ratings (Note1)

- V_{CC} ---------- -0. 5V to + 4.6V
- V_I ---------- - 0. 5V t o + 4. 6V
- V_O (Voltage range applied to any output in the high-impedance or power-off state) ---------- - 0. 3V to + 4. 6V
- V_O(Voltage range applied to any output in the high or slow state)---------- -0.3V to V_{CC}+0.3V
- Input clamp current ---------- -50mA
- Output clamp current ---------- -50mA
- Continuous output current ---------- ±20mA
- Storage Temperature ---------- -65℃ to 150℃

Recommended Operating Conditions

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply voltage	V_{CC}	Operating	0.8		3.6	V
Input voltage	V_I		0		3.6	V
Output voltage	V_O		0		VCC	V
High- level output current	I_{OH}	V_{CC} = 0.8V			-20	uA
		V_{CC} = 1.1V			-1.1	mA
		V_{CC} = 1.4V			-1.7	
		V_{CC} = 1.65V			-1.9	
		V_{CC} = 2.3V			-3.1	
		V_{CC} = 3V			-4	
Low- level output current	I_{OL}	V_{CC} = 0.8V			20	uA
		V_{CC} = 1.1V			1.1	mA
		V_{CC} = 1.4V			1.7	
		V_{CC} = 1.65V			1.9	
		V_{CC} = 2.3V			3.1	
		V_{CC} = 3V			4	
Operating temperature	T_A		-40		85	℃

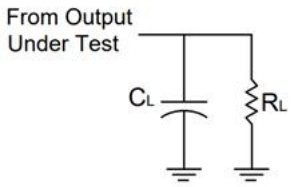
Electrical Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Positive-going input threshold voltage	V_{T+}	V_{CC} = 0.8V	0.3		0.6	V
		V_{CC} = 1.1V	0.53		0.9	
		V_{CC} = 1.4V	0.74		1.11	
		V_{CC} = 1.65V	0.91		1.29	
		V_{CC} = 2.3V	1.37		1.77	
		V_{CC} = 3V	1.88		2.29	
Negative-going input threshold voltage	V_{T-}	V_{CC} = 0.8V	0.1		0.6	V
		V_{CC} = 1.1V	0.26		0.65	
		V_{CC} = 1.4V	0.39		0.75	
		V_{CC} = 1.65V	0.47		0.84	
		V_{CC} = 2.3V	0.69		1.04	
		V_{CC} = 3V	0.88		1.24	
Hysteresis voltage	△VT	V_{CC} = 0.8V	0.07		0.5	V
		V_{CC} = 1.1V	0.08		0.46	
		V_{CC} = 1.4V	0.18		0.56	
		V_{CC} = 1.65V	0.27		0.66	
		V_{CC} = 2.3V	0.53		0.92	
		V_{CC} = 3V	0.79		1.31	
High- level output voltage	V_{OH}	V_{CC} = 0.8~3.6V, I_{OH}= -20uA	V_{CC}-0.1			V
		V_{CC} = 1.1V, I_{OH}= -1.1mA	0.75×V_{CC}			
		V_{CC} = 1.4V, I_{OH}= -1.7mA	1.11			
		V_{CC} = 1.65V, I_{OH}= -1.9mA	1.32			
		V_{CC} = 2.3V, I_{OH}= -2.3mA	2.05			
		V_{CC} = 2.3V, I_{OH}= -3.1mA	1.9			
		V_{CC} = 3V, I_{OH}= -2.7mA	2.72			
		V_{CC} = 3V, I_{OH}= -4mA	2.6			
Low- level output voltage	V_{OL}	V_{CC} = 0.8~3.6V, I_{OL}= 20uA			0.1	V
		V_{CC} = 1.1V, I_{OL}= 1.1mA			0.3×V_{CC}	
		V_{CC} = 1.4V, I_{OL}= 1.7mA			0.31	
		V_{CC} = 1.65V, I_{OL}= 1.9mA			0.31	
		V_{CC} = 2.3V, I_{OL}= 2.3mA			0.31	
		V_{CC} = 2.3V, I_{OL}= 3.1mA			0.44	
		V_{CC} = 3V, I_{OL}= 2.7mA			0.31	
		V_{CC} = 3V, I_{OL}= 4mA			0.44	
Input leakage current	I_I	V_{IN}= 3.6V or GND, V_{CC}= 0~3.6V			0.1	uA
Power off leakage current	I_{OFF}	V_I or V_O=0V to 3.6V, V_{CC}=0V			0.2	uA
Supply current	I_{CC}	V_I= GND or (V_{CC} to 3.6V), I_{OUT}=0,V_{CC}=0.8~3.6V			0.5	uA
Additional supply current per input pin	△I_{CC}	V_I= V_{CC}-0.6V, I_{OUT}=0			40	uA

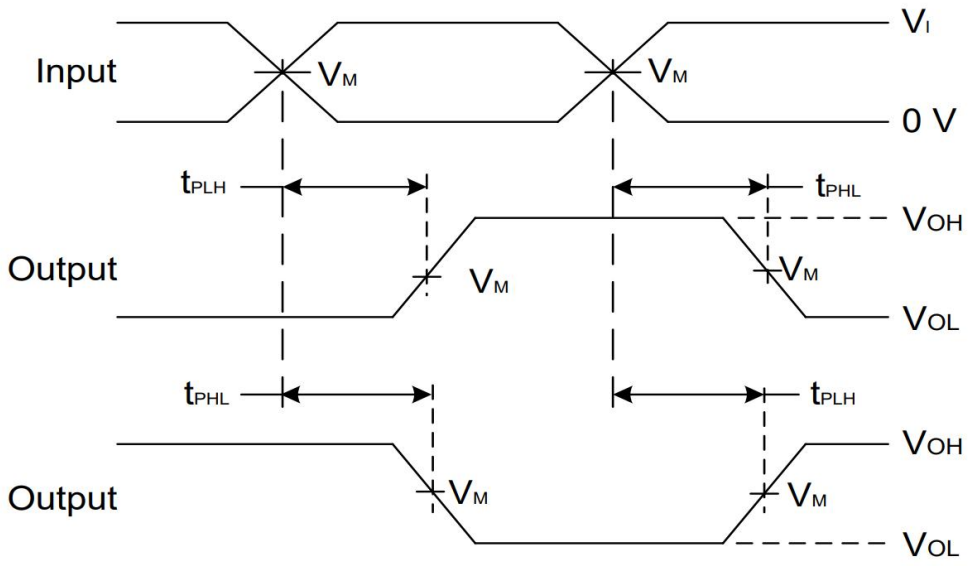
Switching Characteristics

Parameter	Symbol	Test Conditions		Min.	Typ.	Max.	Unit
Propagation delay from input(A or B) to output(Y)	T_{PD}	V_{CC} = 0.8V	C_L=15pF R_L=1MΩ		27.6		ns
		V_{CC} = 1.2V±0.1V		7.8	10.1	14.8	
		V_{CC} = 1.5V±0.1V		5.8	7.4	10.3	
		V_{CC} = 1.8V±0.15V		5	6.1	8.8	
		V_{CC} = 2.5V±0.2V		4	4.7	6.4	
		V_{CC} = 3.3V±0.3V		3.5	4.1	5.4	

Parameter Measurement Information



V_{CC}	INPUTS		V_M	C_L	R_L
	V_I	t_r/t_f			
0.8V	V_{CC}	≦2ns	$V_{CC}/2$	15pF	1MΩ
1.2V ± 0.1V	V_{CC}	≦2ns	$V_{CC}/2$	15pF	1MΩ
1.5V ± 0.1V	V_{CC}	≦2ns	$V_{CC}/2$	15pF	1MΩ
1.8V ± 0.15V	V_{CC}	≦2ns	$V_{CC}/2$	15pF	1MΩ
2.5V ± 0.2V	3V	≦2.5ns	1.5V	15pF	1MΩ
3.3V ± 0.3V	V_{CC}	≦2.5ns	$V_{CC}/2$	15pF	1MΩ



Voltage Waveform Propagation Delay Times

Inverting and Non Inverting Outputs

Notes: A. C_L includes probe and jig capacitance

B. All pulses and supplied at pulse repetition rate ≦ 10MHz

C. The Inputs are measured separately one transition per measurement

D. t_{PLH} and t_{PHL} are the same as t_{PD}

IC Operation Information

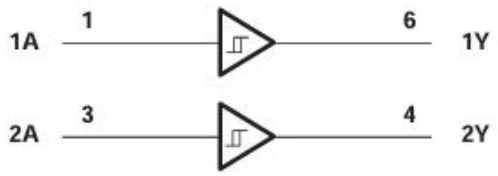
Basic Operation

This device functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input.

The AUP family is the solution to the industry's low power needs in battery-powered portable applications. This family assures a very low static and dynamic power consumption across the entire VCC range of 0.8 V to 3.6 V, resulting in an increased battery life.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered.

Function Block Diagram



Feature Description

- Wide operating V_{CC} range of 0.8V to 3.6V.
- 3.6-V I/O tolerant to support down translation.
- Input hysteresis allows slow input transition and better switching noise immunity at the input.
- Ioff feature allows voltages on the inputs and outputs when V_{CC} is 0 V.
- Low noise due to slower edge rates.

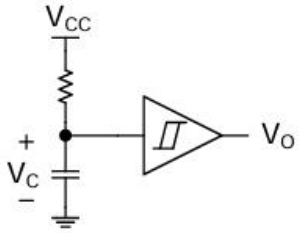
Device Functional Table

INPUTS A	OUTPUT Y
H L	H L

IC Application Information

There are many situations in which a device needs to be initialized or held off for a short time at system turn-on. This application of the FLG74AUP2G17 utilizes the delay created in an RC circuit to hold a line low for a short time when the system is first started, then maintains the line high while the system operates. The FLG74AUP2G17 is ideal for this application because it must be tied directly to the primary supply for correct operation and is designed to draw minimal supply current during operation

Typical Application



Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The drive strength also creates fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

Detailed Design Procedure

1.Recommended Input conditions:

– For specified high and low levels, see (V_{T+} and V_{T-}) in the Electrical Characteristics table.

– Inputs are overvoltage tolerant allowing them to go as high as (V_I max) in the Recommended Operating Conditions table at any valid V_{CC}.

2. Recommended output conditions:

– Load currents should not exceed (I_O max) per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the Absolute Maximum Ratings table.

Power Supply Recommendations

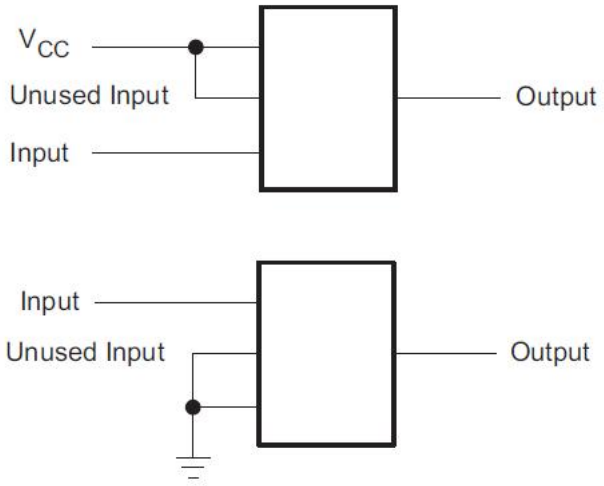
The power supply can be any voltage between the Min and Max supply voltage rating located in the Recommended Operating Conditions table. Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μF is recommended; if there are multiple VCC pins, then 0.01 μF or 0.022 μF is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μF and a 1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

Layout Considerations

When using multiple-bit logic devices, inputs should never float.

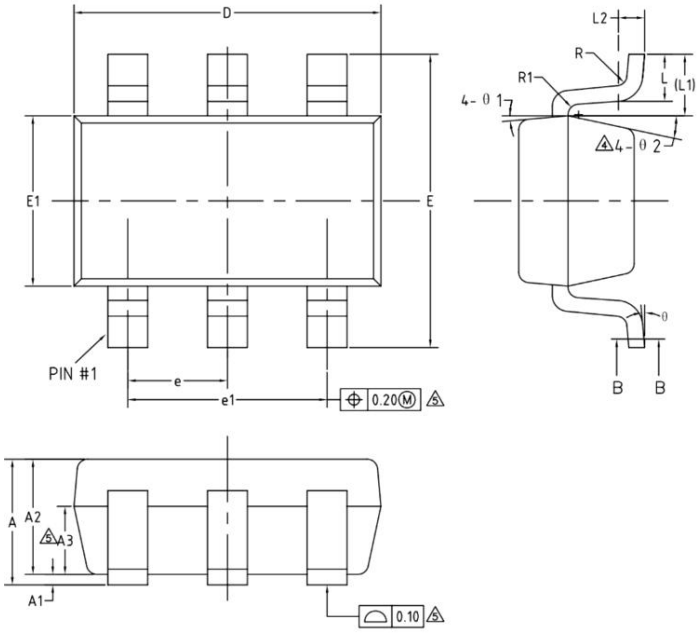
In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Below figure specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or VCC, whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an

output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.



Package Information

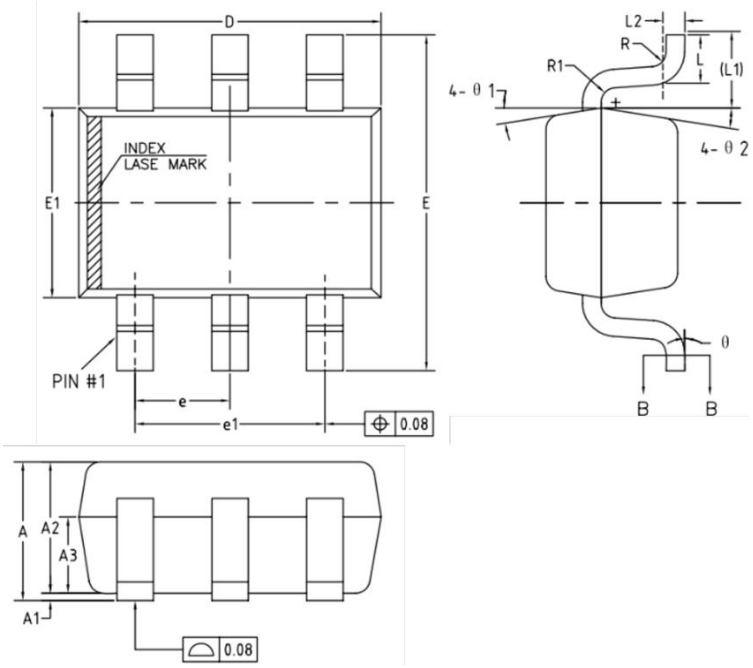
(1) Package Type: SC70-6



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

	SYMBOL	MIN	NOM	MAX
	A	–	–	1.25
	A1	0	–	0.15
	A2	1.00	1.10	1.20
	A3	0.60	0.65	0.70
	b	0.36	–	0.50
	b1	0.36	0.38	0.45
	c	0.14	–	0.20
	c1	0.14	0.15	0.16
	D	2.826	2.926	3.026
	E	2.60	2.80	3.00
	E1	1.526	1.626	1.726
4	e	0.90	0.95	1.00
4	e1	1.80	1.90	2.00
	L	0.35	0.45	0.60
	L1		0.59REF	
	L2		0.25BSC	
3	R	0.10	–	–
3	R1	0.10	–	0.20
	θ	0°	–	8°
	θ 1	3°	5°	7°
4	θ 2	6°	–	14°

(2) Package Type: SC70



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.85	–	1.05
A1	0	–	0.10
A2	0.80	0.90	1.00
A3	0.47	0.52	0.57
2 b	0.22	–	0.29
b1	0.22	0.25	0.28
3 2 c	0.115	–	0.15
3 c1	0.115	0.13	0.14
D	2.02	2.07	2.12
E	2.20	2.30	2.40
E1	1.25	1.30	1.35
e	0.65BSC		
e1	1.30BSC		
L	0.28	0.33	0.38
L1	0.50REF		
L2	0.15BSC		
R	0.10	–	–
R1	0.10	–	0.25
θ	0°	–	8°
θ 1	6°	9°	12°
θ 2	6°	9°	12°

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